

Supporting Information

Achieving long carrier lifetime and high optical gain in all-inorganic CsPbBr₃ perovskite films through top and bottom surface modification

Li Jiang, Zhishan Fang, Haoran Lou, Chen Lin, Zhanhang Chen, Jing Li, Haiping He,* and Zhizhen Ye*

State Key Laboratory of Silicon Materials, School of Materials Science and Engineering, Zhejiang University, Hangzhou 310027, China

*Corresponding authors. Email: hphe@zju.edu.cn, yezz@zju.edu.cn

Supplementary Note 1

The grain size of perovskite films could be estimated by Debye-Scherrer equation: $D = k \lambda / B \cos \theta$, where $k = 0.89$ is the Scherrer constant, $\lambda = 0.15406$ nm is X-ray wavelength and B is the FWHM of diffraction peak. In our films, the B values of 15° and 30.5° peaks are 0.18° and 0.22° respectively. The grain size of films is thus determined to be roughly 47 nm.

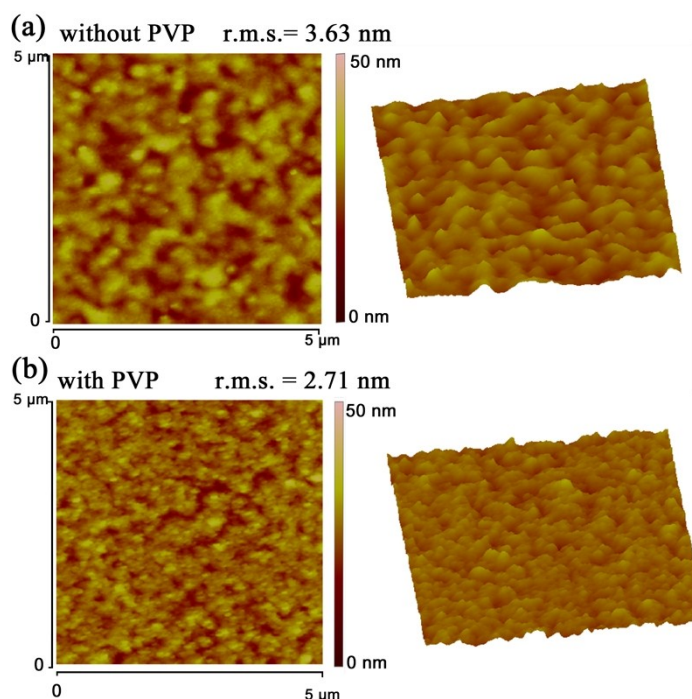


Figure S1. AFM images from perovskite film (a) without a PVP layer and (b) with a PVP layer on the substrate.

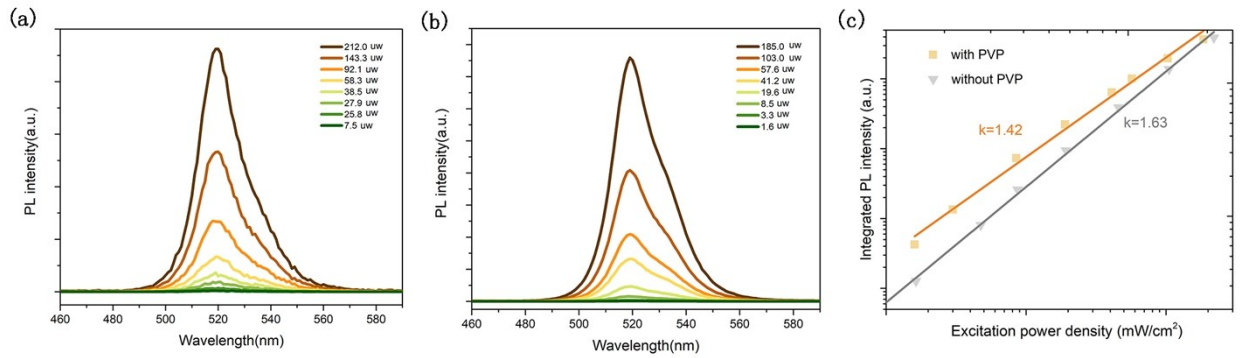


Figure S2. Excitation density-dependent PL measurements from perovskite film (a) without a PVP layer or (b) with a PVP layer. (c) Fitting result of excitation density-dependent PL measurements.

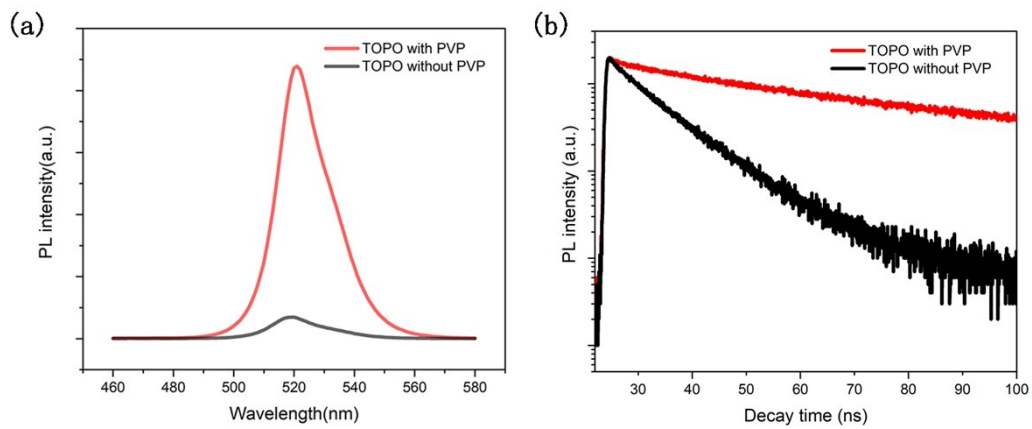


Figure S3. (a) Steady-state PL spectra (b) Transient PL decay measurements from TOPO-treated perovskite films with or without a PVP layer.

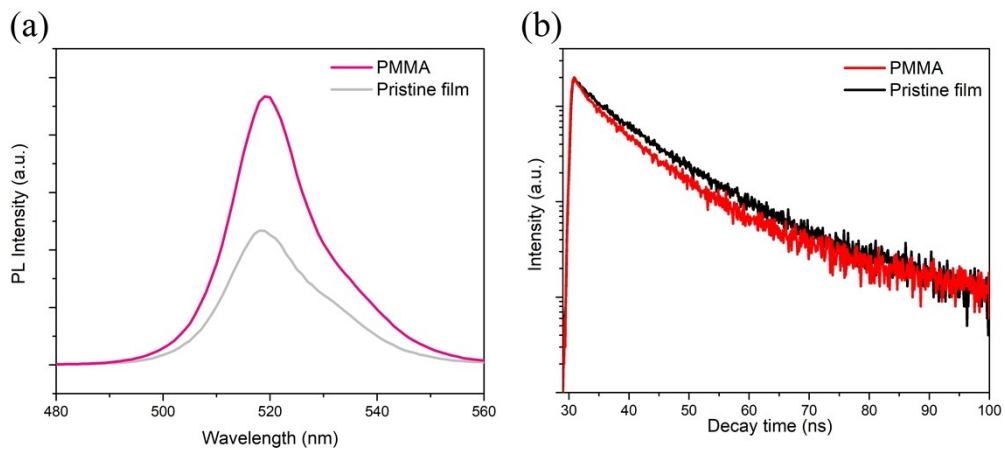


Figure S4. (a) Steady-state PL spectra (b) Transient PL decay from PMMA-treated perovskite film and pristine film.

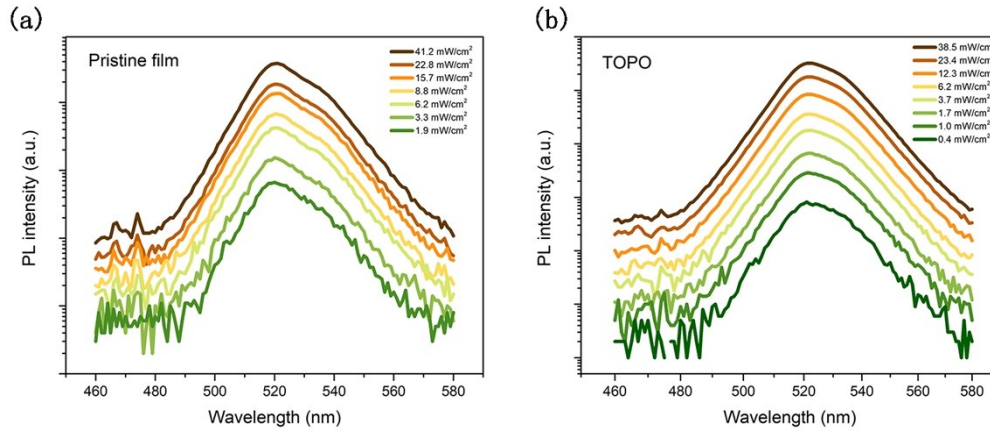


Figure S5. Excitation density-dependent PL measurements from (a) pristine film and (b) TOPO-treated perovskite film.

Table S1. Gain coefficient and carrier lifetime comparison of CsPbBr₃ perovskite film as optical gain medium

	Gain (cm ⁻¹)	Carrier lifetime (ns)	Publish year	Ref.
CsPbBr ₃ single crystal	38	8	2019	1
CsPbBr ₃ NCs film	450±30	~1.5	2015	2
CsPbBr ₃ NCs film		11	2015	3
CsPbBr ₃ NCs film		~7	2016	4
CsPbBr ₃ NCs film		~8	2016	5
CsPbBr ₃ NCs film	~580	~5	2016	6
CsPbBr ₃ NCs film	98	3.1	2015	7
CsPbBr ₃ NCs film		1.6	2018	8
CsPbBr ₃ NCs film		12.52	2018	9
CsPbBr ₃ NCs film	51	3.64; 8.16	2018	10
CsPbBr ₃ NCs film	~502		2018	11
CsPbBr ₃ film		21.99	2017	12
CsPbBr ₃ film		2.01-3.53	2017	13
CsPbBr ₃ film	100 (10 K)		2017	14
CsPbBr ₃ film	>300	1-5	2018	15
Our work	694	44	2019	

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